
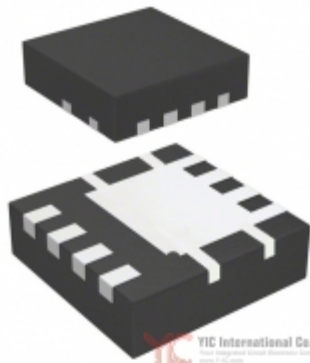




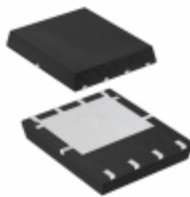

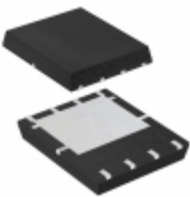




|   |                                |  |
|---|--------------------------------|--|
|   | <b>DMT6010LFG-7</b>            |  |
|   | <b>Hersteller-Teilenummer:</b> | DMT6010LFG-7   |
|  | <b>Hersteller / Marke:</b>     | Diodes Incorporated  |
|   | <b>Teil der Beschreibung:</b>  | MOSFET N-CH 60V 13A POWERDI  |
|   | <b>Datenblätter:</b>           |  <a href="#">DMT6010LFG-7.pdf</a> |
|   | <b>RoHs Status:</b>            | Bleifrei / RoHS-konform  |
|   | <b>Lagerzustand:</b>           | New original, 16573 pcs Stock Available.   |
|   | <b>Liefern von:</b>            | Hong Kong  |
|   | <b>Versandweg:</b>             | DHL/Fedex/TNT/UPS/EMS  |
| Image may be representation. See specs for product details.                       |                                |  |

### Spezifikationen

|   |   |
|---|---|
| Teilenummer                                     | DMT6010LFG-7  |
| Hersteller                                      | Diodes Incorporated   |
| Beschreibung                                    | MOSFET N-CH 60V 13A POWERDI   |
| Kategorie                                       | <a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a> |
| Teilstatus                                      | 16573 pcs Stock   |
| Serie   | -   |
| Technologie                                     | MOSFET (Metal Oxide)  |
| Betriebstemperatur                              | -55°C ~ 150°C (TJ)  |
| Befestigungsart                                 | Surface Mount   |
| Verpackung / Gehäuse                            | 8-PowerWDFN   |
| Supplier Device-Gehäuse                         | PowerDI3333-8   |
| Verlustleistung (max)                           | 2.2W (Ta), 41W (Tc)   |
| Typ FET   | N-Channel   |
| FET-Merkmal                                     | -   |
| Drain-Source-Spannung (Vdss)                    | 60V   |
| Strom - Ununterbrochener Abfluss (Id) bei 25 °C | 13A (Ta), 30A (Tc)  |
| Rds On (Max) @ Id, Vgs                          | 7.5 mOhm @ 20A, 10V   |
| VGS (th) (Max) @ Id                             | 2V @ 250µA  |
| Gate Charge (Qg) (Max) @ Vgs                    | 41.3nC @ 10V  |
| Eingabekapazität (Ciss) (Max) @ Vds             | 2090pF @ 30V  |
| Antriebsspannung (Max Rds On, Min Rds On)       | 4.5V, 10V   |
| Vgs (Max)                                       | ±20V  |
| Verpackung                                      | Tape & Reel (TR)  |



















































DMT6010LFG-7 ist neu im Original, Suche DMT6010LFG-7 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie DMT6010LFG-7 Diodes Incorporated mit Garantie und Vertrauen. Anfrage DMT6010LFG-7: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

|  |   |  |  |
|--|---|--|--|
|  <p><b>DMT6010LSS</b><br/>Diodes Incorporated<br/>DMT6010LSS DIODES</p>                       |  <p><b>DMT6010LPS-13</b><br/>Diodes Incorporated<br/>MOSFET N-CH 60V 13.5A</p>   |  <p><b>DMT6012LPS-13</b><br/>Diodes Incorporated<br/>MOSFET N-CH 60V POWERDI</p> |  <p><b>DMT6009LPS-13</b><br/>Diodes Incorporated<br/>MOSFET N-CHA 60V 10.6A POWERDI</p>       |
|  <p><b>DMT6010LSS-13</b><br/>Diodes Incorporated<br/>MOSFET BVDSS: 41V 60V SO-8 T&amp;R 2</p> |  <p><b>DMT6010SCT</b><br/>Diodes Incorporated<br/>MOSFET N-CHA 60V 98A TO220</p> |  <p><b>DMT6010LFG</b><br/>Diodes Incorporated<br/>DMT6010LFG DIODES</p>          |  <p><b>DMT6009LSS-13</b><br/>Diodes Incorporated<br/>MOSFET BVDSS: 41V 60V,SO-8,T&amp;R,2</p> |

### heiße Teile

Mehr

|   |  |   |  |  |
|---|--|---|--|--|
|  DMT3009LFVW   |  DMT3009LFVW-13 |  DMT3009LFVW-7 |  DMT3020LPS    |  DMT3020LSD     |
|  DMT32M5LPS    |  DMT4011LFG-7   |  DMT40M9LPS-13 |  DMT6004LPS-13 |  DMT6004SPS     |
|  DMT6004SPS-13 |  DMT6005LPS     |  DMT6005LPS-13 |  DMT6005LSS    |  DMT6008LFG     |
|  DMT6008LFG-7  |  DMT6009LCT     |  DMT6009LFG    |  DMT6009LFG-13 |  DMT6009LK3     |
|  DMT6009LPS    |  DMT6009LPS-13  |  DMT6009LSS    |  DMT6010LFG    |  DMT6010LFG-13  |
|  DMT6010LPS-13 |  DMT6010LSS     |  DMT6010LSS-13 |  DMT6010SCT    |  DMT6015LFV     |
|  DMT6015LFV-13 |  DMT6015LFV-7   |  DMT6015LPS-13 |  DMT6015LSS    |  DMT6015LSS-13  |
|  DMT6016LSS    |  DMT6016LSS-13  |  DMT6017LSS    |  DMT6017LSS-13 |  DMT69M8LSS     |
|  DMT8012LSS    |  DMTH3004LK3    |  DMTH3004LK3Q  |  DMTH4004LK3   |  DMTH4004LK3-13 |
|  DMTH4004LPS   |  DMTH4004LPS-13 |  DMTH4004SCTB  |  DMTH4004SPS   |  DMTH4005SK3    |

Contact us:[Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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